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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/572,655	03/06/2007	Dominik Eisert	5367-223PUS	4408

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EXAMINER

LAM, CATHY N

ART UNIT	PAPER NUMBER
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2811

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04/27/2009

PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary	Application No.	Applicant(s)	
	10/572,655	EISERT ET AL.	
	Examiner	Art Unit	
	CATHY N. LAM	2811	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 1/15/2009.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1,2,4-8 and 10-61 is/are pending in the application.
- 4a) Of the above claim(s) 19-43 is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-2,4-8,10-18,44-61 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) |
| 2) <input type="checkbox"/> Notice of Draftperson's Patent Drawing Review (PTO-948) | Paper No(s)/Mail Date. _____ |
| 3) <input checked="" type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08) | 5) <input type="checkbox"/> Notice of Informal Patent Application |
| Paper No(s)/Mail Date <u>12/19/2008,02/02/2009</u> . | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Claim Rejections - 35 USC § 112

1. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

2. Claim 45 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

3. The claimed limitation of “the semiconductor chip is free of a growth substrate of the epitaxial multilayer structure”, as recited in claims 45, 47, is unclear as to what “the semiconductor chip is free of a growth substrate of the epitaxial multilayer structure” applicant refers.

Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

5. Claims 1-2, 4-8,10-18,44-61 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lester (U.S. Patent No. 6,291,839).

Regarding claim 1, Lester discloses in figure 5 a radiation (light) emitting semiconductor chip comprising:

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an epitaxial multilayer structure 16, 14, 8, fig. 5 comprising:
an active radiation (light) generating layer 14
a first main face (bottom surface of layer 8) and
a second main face (upper surface of layer 16) remote from the first main face for
coupling out radiation generating in the active radiation generating layer 14, and
a reflective layer 9 or interface, and
wherein the first main face of the multilayer structure is coupled to the reflective layer 9
or interface, and
wherein a region 16 of the multilayer structure that adjoins the second main face of the
multilayer structure is patterned by one or two dimensional fig.1 depressions forming
convex elevations fig.5.

It is noted that the term "thin film" is a broad limitation herein because there is no recitation of how thin this thin film is in specific. Therefore, the film disclosed by Lester in figure 5 can be construed as "thin film".

Lester discloses the claimed invention except for the convex elevations having a height (h1) at least as large as a distance (h2) between the patterned region and the active, radiation-generating layer.

It would have been an obvious matter of design choice to include the convex elevations having a height (h1) at least as large as a distance (h2) between the patterned region and the active, radiation-generating layer, since such a modification would have involved a mere change in the size or shape of a component. A change in

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size or shape is generally recognized as being within the level of ordinary skill in the art.

In re Rose, 105 USPQ 237 (CCPA 1955).

Regarding claim 46, Lester discloses a radiation-emitting thin-film semiconductor chip comprising an epitaxial multilayer structure and a reflective layer or interface, the epitaxial multilayer structure comprising:

an active, radiation-generating layer 14,

a first main face (bottom surface of layer 8), and

a second main face (upper surface of layer 16) remote from the first main face for coupling out the radiation generated in the active, radiation-generating layer 14,

wherein the first main face of the multilayer structure is coupled to the reflective layer 9 or interface, and

wherein a region of the multilayer structure that adjoins the second main face of the multilayer structure is patterned by either one- or two dimensional (figs.1,5) depressions forming convex elevations.

It is noted that the term "thin film" is a broad limitation herein because there is no recitation of how thin this thin film is in specific. Therefore, the film disclosed by Lester in figure 5 can be construed as "thin film".

Lester discloses the claimed invention except for the convex elevations having an inclination angle (B) of between approximately 30° and approximately 70°.

It would have been an obvious matter of design choice to include the convex elevations having an inclination angle (B) of between approximately 30° and approximately 70°, since such a modification would have involved a mere change in the size or shape of a component. A change in size or shape is generally recognized as being within the level of ordinary skill in the art. *In re Rose*, 105 USPQ 237 (CCPA 1955).

Regarding claims 2, 48, Lester discloses the semiconductor chip as claimed in claim 1, further comprising a carrier element coupled to the first main face, wherein the reflective layer 9 or interface is arranged between the carrier element and the multilayer structure.

It is noted that the substrate as shown in figure 5 can function as "carrier substrate" because it is connected to reflector 9, which enables the substrate to electrically connect with the electrical source or circuit to drive the light emitting device

Regarding claims 4, 5, 49, 50, Lester discloses in figure 5 the semiconductor chip as claim 1, wherein the elevations of layer 16 have a form of truncated pyramids or truncated cones or a trapezoidal cross sectional form or a form of cones or a triangular cross-section form fig.5.

Regarding claim 6, Lester discloses in figure 5 the elevations 16 have a form of truncated cones, not of a circle or sphere segment cross sectional form as claimed.

However *In re Dailey*, 357 F.2d 669, 149 USPQ 47 (CCPA 1966), the Court held that the changes in shape was a matter of choice which a person of ordinary skill in the

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art would have found obvious absent persuasive evidence (MPEP 2144.04, page 2100-137, Rev. 5, August, 2006).

It would have been obvious to one having ordinary skill in the art at the time of the present invention was made, to modify Lester by including the elevation having the circle segment cross sectional form, since this involves only routine skill in the art.

Regarding claims 7, 8, 51, Lester discloses in figure 5 the elevations have an aperture angle of certain degree(s), not necessarily between approximately 30° and approximately 70° or between approximately 40° and approximately 50°.

It would have been obvious to one having ordinary skill in the art at the time the invention was made, to modify Lester by including the elevations having an aperture angle of between approximately 30° and approximately 70° or between approximately 40° and approximately 50°, since it has been held that where the general conditions of a claim are disclosed in the prior art discovering the optimum or working ranges involves only routine skill in the art. In re Aller, 105 USPQ 233.

Regarding claims 10, 52, 53, Lester discloses in figure 5 the elevations 16 have certain heights. Lester does not disclose the height (h1) of the elevations being approximately as large as or twice as large as the distance (h2) between the patterned region of the multilayer structure and the active, radiation generating layer.

It would have been obvious to one having ordinary skill in the art at the time of the invention was made, to modify Lester by including the height of the elevations being approximately twice as large as the distance between the non patterned region of the multilayer structure and the active, radiation generating layer and the elevation, since it

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has been held that discovering an optimum value of a result effective variable involves only routine skill in the art. In re Boesch, 617 F.2d 272, 205 USPQ 215 (CCPA 1980).

Regarding claims 11, 54, Lester discloses in figure 5 the elevations have a light emitted opening dimension.

But Lester does not disclose the cell size (d) of the elevations being at most approximately five times as large as the height (h₁) of the elevations.

It would have been obvious to one having ordinary skill in the art at the time of the invention was made, to modify Lester by including a light emitted opening dimension of the elevations being at most approximately five times as large as the height of the elevations, since it has been held that discovering an optimum value of a result effective variable involves only routine skill in the art. In re Boesch, 617 F.2d 272, 205 USPQ 215 (CCPA 1980).

Regarding claims 12, 55, Lester discloses in figure 5 the elevations have a light emitted opening dimension. But Lester does not disclose the cell size of the elevations being at most approximately three times as large as the height of the elevations.

It would have been obvious to one having ordinary skill in the art at the time of the invention was made, to modify Lester by including the light emitted opening dimension of the elevations being at most approximately three times as large as the height of the elevations, since it has been held that discovering an optimum value of a result effective variable involves only routine skill in the art. In re Boesch, 617 F.2d 272, 205 USPQ 215 (CCPA 1980).

Regarding claim 13, as best understood, Lester discloses in figure 5 the

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reflective layer 9 or interface coupled to the first main area of the multilayer structure has a reflection at least 70% (column 2, lines 65-66).

Regarding claims 14, 56, Lester discloses in column 2, lines 65-67 the layer 9 coupled to the first main area of the multilayer structure has a reflection of at least 70%. Lester, however does not exclusively discloses a reflectivity of at least 85%.

It would have been obvious to one having ordinary skill in the art at the time of the invention was made, to modify Lester by including the layer or interface couple to the first main area of the multilayer structure as a reflectivity of at least 85%, since it has been held that discovering an optimum value of a result effective variable involves only routine skill in the art. In re Boesch, 617 F.2d 272, 205 USPQ 215 (CCPA 1980).

Regarding claim 15, Lester discloses in figure 5 the multilayer structure is applied on a carrier substrate (substrate) either directly by its first main face or via a reflective layer.

It is noted that the substrate as shown in figure 5 can function as "carrier substrate" because it is connected to reflector 9, which enables the substrate to electrically connect with the electrical source or circuit to drive the light emitting device.

Regarding claim 16, Lester discloses in figure 5 the reflective layer 9 is also a conductive layer (col.3 lines 49-50) which can serve as a contact layer of the semiconductor component.

Regarding claim 17, Lester discloses in figure 5 a conductive transparent layer 20 (column 3, lines 41-48) applied onto the second main face of the multilayer structure.²

Regarding claims 18, 60, Lester discloses a conductive transparent chip as claimed in claim 1, further comprising a transparent protective layer 22 (col.4 lines 62-66) applied onto the second main face of the multilayer structure.

Regarding claim 44, Lester discloses the semiconductor chip as claimed in claim 1, wherein each of the convex elevations is defined by two-dimensional depressions fig.1.

Regarding claims 45, 47, Lester discloses the semiconductor chip as claimed in claim 1, wherein the semiconductor chip is free of a growth substrate of the epitaxial multilayer structure fig.5.

Regarding claim 57, Lester discloses the semiconductor chip as claimed in claim 47, wherein the multilayer structure is applied onto a carrier substrate either directly by the first main face or via the reflective layer or interface fig.5.

Regarding claim 58, Lester discloses the semiconductor chip as claimed in claim 57, wherein the reflective layer 9 or interface or the carrier substrate serves as a contact layer of the semiconductor chip, as well known in the art, in order for the semiconductor chip enables to contact with the electrical source or circuit to drive the light emitting device.

Regarding claim 59, Lester discloses the semiconductor chip as claimed in claim 46, further comprising a conductive, transparent layer 22 (col.4 lines 62-66) applied onto the second main face of the multilayer structure fig.4.

Regarding claim 61, Lester discloses the semiconductor chip as claimed in claim 46, wherein the multilayer structure comprises a material or a plurality of different materials based on GaN (abstract).

Response to Arguments

6. Applicant's arguments with respect to claims 1-2, 4-8, 10-18, 44-61 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

7. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire **THREE MONTHS** from the mailing date of this action. In the event a first reply is filed within **TWO MONTHS** of the mailing date of this final action and the advisory action is not mailed until after the end of the **THREE-MONTH** shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than **SIX MONTHS** from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to CATHY N. LAM whose telephone number is (571)270-5021. The examiner can normally be reached on M-F 7:30AM to 5PM.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, LYNNE GURLEY can be reached on 571-272-1670. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

CL

4/26/2009

/Cuong Q Nguyen/

Primary Examiner, Art Unit 2811